

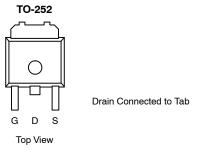
PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$r_{DS(on)}\left(\Omega\right)$	I <sub>D</sub> (A) <sup>b</sup>		
30	0.006 @ V <sub>GS</sub> = 10 V	70		
	0.009 @ V <sub>GS</sub> = 4.5 V	70		

#### **FEATURES**

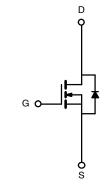
- TrenchFET® Power MOSFET
- High Current
- 100% R<sub>g</sub> Tested

#### **APPLICATIONS**

- DC/DC Converters
  - Optimized For Low Side
- Synchronous Rectifiers







Ordering Information: SUD70N03-06P

N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V <sub>DS</sub>	30	.,	
Gate-Source Voltage		V <sub>GS</sub>	±20		
0.11	T <sub>C</sub> = 25°C		70		
Continuous Drain Current <sup>a</sup>	T <sub>C</sub> = 100°C	- I <sub>D</sub>	70 <sup>b</sup>		
Pulsed Drain Current		I <sub>DM</sub>	100	А	
Continuous Source Current (Diode Conduction) <sup>a</sup>		Is	27		
Avalanche Current, single pulse	1 04 11	I <sub>AS</sub>	45		
Avalanche Energy, single pulse	L = 0.1 mH	E <sub>AS</sub>	101	mJ	
	T <sub>C</sub> = 25°C		88		
Maximum Power Dissipation	T <sub>A</sub> = 25°C	P <sub>D</sub>	8.3 <sup>a</sup>	W	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 175	°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
	t ≤ 10 sec		15	18		
Maximum Junction-to-Ambient <sup>a</sup>	Steady State	R <sub>thJA</sub>	40	50	°C/W	
Maximum Junction-to-Case		R <sub>thJC</sub>	1.4	1.7		

#### Notes

Surface Mounted on FR4 Board,  $t \le 10$  sec.

Limited by package.

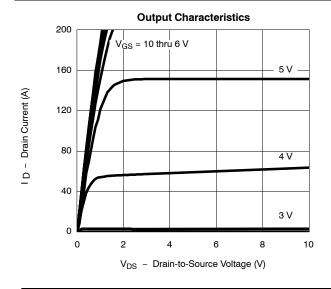
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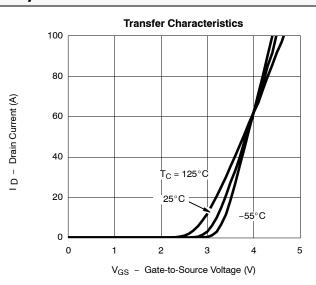
Parameter	Symbol	Test Condition	Min	Typa	Max	Unit
Static			•	1		
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0 \text{ V, } I_D = 250 \mu\text{A}$	30			v
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.0		3.0	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA
Zero Gate Voltage Drain Current	i .	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$			1	<u> </u>
	DSS	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 125°C			50	μΑ
On-State Drain Current <sup>b</sup>	I <sub>D(on)</sub>	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	50			Α
Drain-Source On-State Resistance <sup>b</sup>		$V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$		0.0046	0.006	
	r <sub>DS(on)</sub>	$V_{GS}$ = 10 V, $I_D$ = 20 A, $T_J$ = 125°C			0.0105	Ω
		$V_{GS} = 4.5 \text{ V}, I_D = 20 \text{ A}$		0.0072	0.009	1
Forward Transconductanceb	9fs	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 20 A	20			S
Dynamic <sup>a</sup>						
Input Capacitance	C <sub>iss</sub>			3100		
Output Capacitance	C <sub>oss</sub>	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$		565		pF
Reverse Transfer Capacitance	C <sub>rss</sub>			255		
Total Gate Charge <sup>c</sup>	Qg			21	30	nC
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>	$V_{DS} = 15 \text{ V}, \ V_{GS} = 4.5 \text{ V}, \ I_D = 50 \text{ A}$		10		
Gate-Drain Charge <sup>c</sup>	Q <sub>gd</sub>			7.5		
Gate Resistance	R <sub>g</sub>	f = 1 MHz	0.9 2.0		3.4	Ω
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>			12	20	
Rise Time <sup>c</sup>	t <sub>r</sub>	$V_{DD} = 15 \text{ V}, R_L = 0.3 \Omega$		12	20	ns
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>	$I_D \cong 50 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 2.5 \Omega$		30	45	
Fall Time <sup>c</sup>	t <sub>f</sub>			10	15	
Source-Drain Diode Ratings an	d Characteristi	c (T <sub>C</sub> = 25°C)				
Pulsed Current	I <sub>SM</sub>				100	Α
Diode Forward Voltage <sup>b</sup>	V <sub>SD</sub>	I <sub>F</sub> = 100 A, V <sub>GS</sub> = 0 V		1.2	1.5	V
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 50 A, di/dt = 100 A/μs		35	70	ns

#### Notes

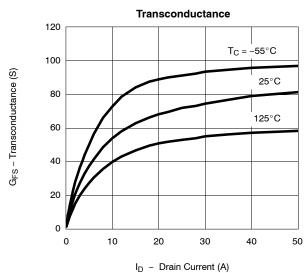
- Guaranteed by design, not subject to production testing.
- b. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2%.
- c. Independent of operating temperature.

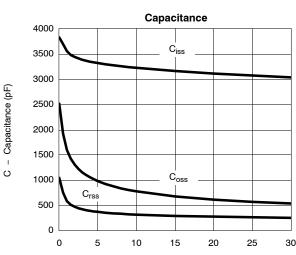
### TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)



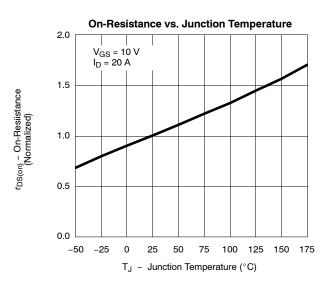


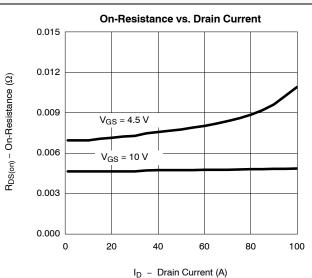
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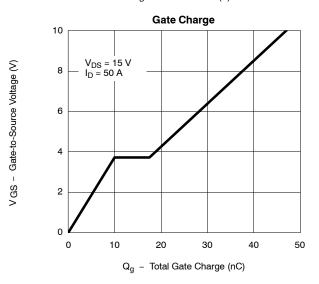


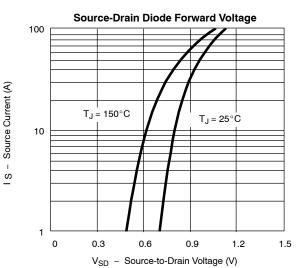


 $V_{DS}$  - Drain-to-Source Voltage (V)



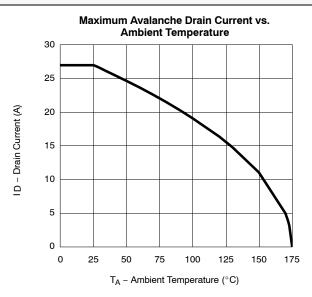


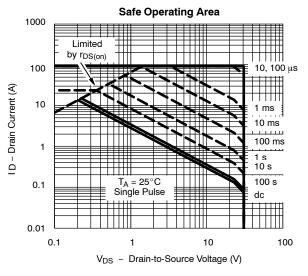


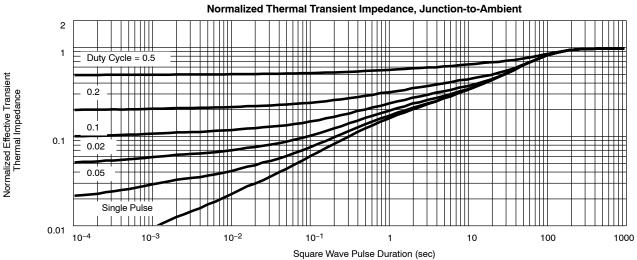


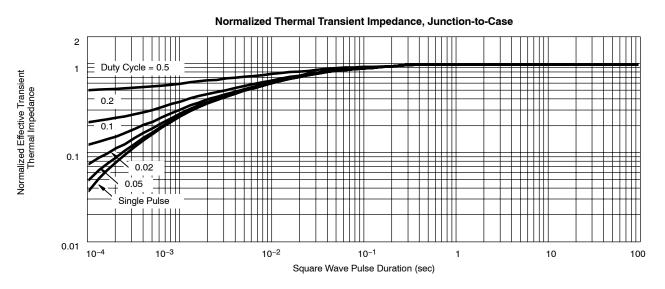


### THERMAL RATINGS











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